

Technical Data Sheet

ACS Material Graphene on Silicon Substrate

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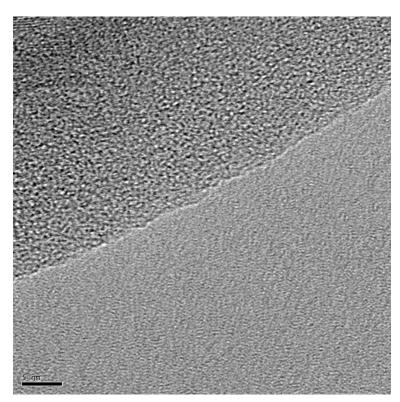
1. Preparation Method

Graphene on Si substrate was prepared by the following steps:

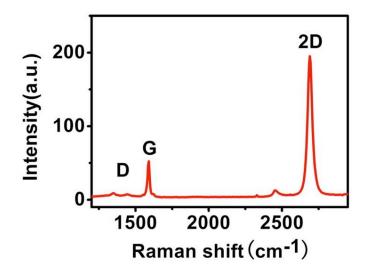
- 1) Monolayer graphene grown on copper foil
- 2) Deposit PMMA and cure
- 3) Remove Cu by etching process
- 4) Wash PMMA/Graphene in DI water
- 5) Redeposit PMMA/Graphene onto Si substrate and cure
- 6) Remove PMMA with acetone

2. Characterizations

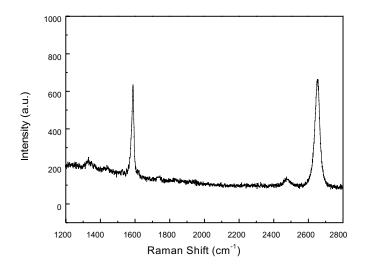
Layers:	Predominantly single-layer graphene
Sheet Resistance (Ω/sq):	<600
Custom Order (Ω/sq):	<300
Transparency (%):	>95



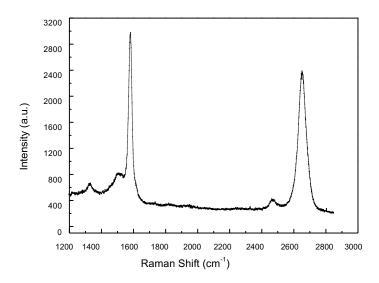
Typical TEM Image of ACS Material Single Layer Graphene Film



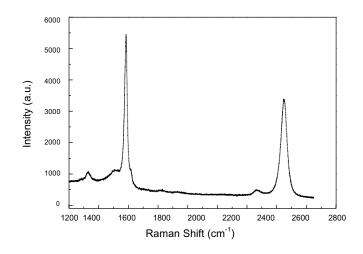
Typical Raman Spectrum of ACS Material Single Layer Graphene Film



Typical Raman Spectra of ACS Material 2 Layer Graphene Film (Prepared by CVD Method)



Raman Spectra of ACS Material 3~5 Layer Graphene Film (Prepared by CVD Method)



Raman Spectra of ACS Material 6~8 Layer Graphene Film (Prepared by CVD Method)

3. Application Fields

- 1) Catalyst
- 2) Supercapacitors
- 3) Solar energy
- 4) Graphene semiconductor chips
- 5) Conductive graphene film
- 6) Graphene computer memory
- 7) Biomaterials
- 8) Transparent conductive coatings

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